

ISOTOP<sup>®</sup> Buck chopper Trench + Field Stop IGBT3

## $V_{CES} = 1200V$ $I_{C} = 100A$ @ Tc = 80°C

# 



#### Application

- AC and DC motor control
- Switched Mode Power Supplies

#### Features

- Trench + Field Stop IGBT3 Technology
  - Low voltage drop
  - Low tail current
  - Switching frequency up to 20 kHz
  - Soft recovery parallel diodes
  - Low diode VF
  - Low leakage current
  - RBSOA and SCSOA rated
- ISOTOP<sup>®</sup> Package (SOT-227)
- Very low stray inductance
- High level of integration

### Benefits

- Low conduction losses
- Stable temperature behavior
- Very rugged
- Direct mounting to heatsink (isolated package)
- Low junction to case thermal resistance
- Easy paralleling due to positive  $T_C$  of  $V_{CEsat}$
- RoHS Compliant

### Absolute maximum ratings

Symbol	Parameter			Max ratings	Unit
V <sub>CES</sub>	Collector - Emitter Breakdown Voltage			1200	V
I <sub>C1</sub>	Continuous Collector Current $T_{C}$		$T_C = 25^{\circ}C$	140	
I <sub>C2</sub>	Continuous Conector Current	$T_C = 80^{\circ}C$	100	А	
I <sub>CM</sub>	Pulsed Collector Current	Ilsed Collector Current To			
$V_{GE}$	Gate – Emitter Voltage			±20	V
P <sub>D</sub>	Maximum Power Dissipation		$T_C = 25^{\circ}C$	480	W
IF <sub>AV</sub>	Maximum Average Forward Current	Duty cycle=0.5	$T_C = 80^{\circ}C$	27	А
IF <sub>RMS</sub>	RMS Forward Current (Square wave, 50% duty)			34	Α

CAUTION: These Devices are sensitive to Electrostatic Discharge. Proper Handling Procedures Should Be Followed.



### All ratings (a) $T_j = 25^{\circ}C$ unless otherwise specified

### **Electrical Characteristics**

Symbol	Characteristic	Test Conditions		Min	Тур	Max	Unit
I <sub>CES</sub>	Zero Gate Voltage Collector Current	$V_{GE} = 0V, V_{CE} = 1200V$				5	mA
V <sub>CE(sat)</sub>	Collector Emitter saturation Voltage	VGE 15 V	$T_j = 25^{\circ}C$	1.4	1.7	2.1	V
			$T_j = 125^{\circ}C$		2.0		v
V <sub>GE(th)</sub>	Gate Threshold Voltage	$V_{GE} = V_{CE}, I_C = 4mA$		5.0		6.5	V
I <sub>GES</sub>	Gate – Emitter Leakage Current	$V_{GE} = \pm 20V, V_{CE} = 0V$				400	nA

### **Dynamic Characteristics**

Symbol	Characteristic	Test Conditions	Min	Тур	Max	Unit
Cies	Input Capacitance	$V_{GE} = 0V$		7200		
C <sub>oes</sub>	Output Capacitance	$V_{CE} = 25V$		400		pF
C <sub>res</sub>	Reverse Transfer Capacitance	f = 1 MHz		300		
T <sub>d(on)</sub>	Turn-on Delay Time	Resistive Switching (25°C)		260		
Tr	Rise Time	$V_{GE} = 15V$ $V_{GE} = 600V$		30		ns
T <sub>d(off)</sub>	Turn-off Delay Time	$V_{Bus} = 600V$ $I_{C} = 100A$ $R_{G} = 3.9\Omega$		420		
T <sub>f</sub>	Fall Time			70		
T <sub>d(on)</sub>	Turn-on Delay Time	Inductive Switching (125°C)		290		
Tr	Rise Time	$V_{GE} = 15V$ $V_{Bus} = 600V$ $I_{C} = 100A$ $R_{G} = 3.9\Omega$		45		ns
T <sub>d(off)</sub>	Turn-off Delay Time			520		
T <sub>f</sub>	Fall Time			90		
Eon	Turn-on Switching Energy			10		mJ
E <sub>off</sub>	Turn-off Switching Energy			12		111J



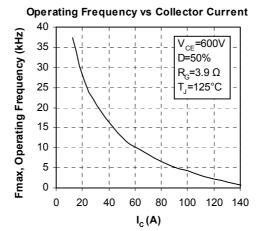
### Chopper diode ratings and characteristics

Symbol	Characteristic	<b>Test Conditions</b>		Min	Тур	Max	Unit
	Diode Forward Voltage	$I_F = 30A$			2.0	2.5	
V <sub>F</sub>		$I_F = 60A$			2.3		V
		$I_F = 30A$	$T_{i} = 125^{\circ}C$		1.8		
I <sub>RM</sub>	Maximum Reverse Leakage Current	$V_{R} = 1200V$	$T_j = 25^{\circ}C$			250	
IRM		$V_{R} = 1200V$	$T_{j} = 125^{\circ}C$			500	μA
C <sub>T</sub>	Junction Capacitance	$V_{R} = 200V$			32		pF
	Reverse Recovery Time	$I_F=1A, V_R=30V$ di/dt=100A/µs	$T_j = 25^{\circ}C$		31		
t <sub>rr</sub>	D	Т	$T_i = 25^{\circ}C$		370		ns
	Reverse Recovery Time		$T_{i} = 125^{\circ}C$		500		
I <sub>RRM</sub>	Maximum Reverse Recovery Current	$I_F = 30A$	$T_j = 25^{\circ}C$		5		А
<sup>1</sup> RRM	Waximum Reverse Recovery Current	$V_{\rm R} = 800 V$	$T_{i} = 125^{\circ}C$		12		Λ
0	Povora Popovoru Chargo	$di/dt = 200 A/\mu s$	$T_j = 25^{\circ}C$		660		nC
Q <sub>rr</sub>	Reverse Recovery Charge		$T_{j} = 125^{\circ}C$		3450		IIC
t <sub>rr</sub>	Reverse Recovery Time	$I_F = 30A$ $V_R = 800V$ $di/dt = 1000A/\mu s$			220		ns
Q <sub>rr</sub>	Reverse Recovery Charge		$T_{j} = 125^{\circ}C$		4650		nC
I <sub>RRM</sub>	Maximum Reverse Recovery Current				37		А

### Thermal and package characteristics

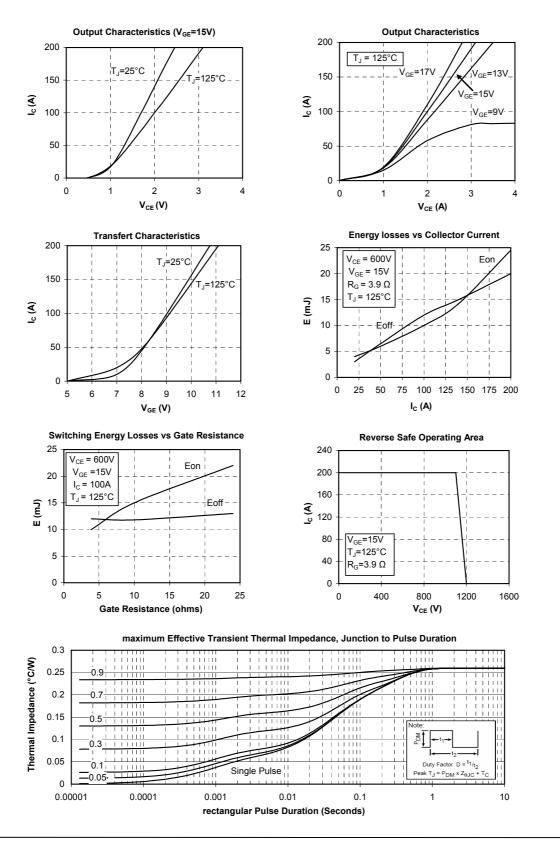
Symbol	Characteristic		Min	Тур	Max	Unit	
R <sub>thJC</sub>	Junction to Case Thermal Resistance IGBT Diode			0.26			
		Diode			1.1	°C/W	
R <sub>thJA</sub>	Junction to Ambient (IGBT & Diode)				20		
V <sub>ISOL</sub>	RMS Isolation Voltage, any terminal to case t =1 min, 50/60Hz		2500			V	
$T_J, T_{STG}$	Storage Temperature Range		-55		150	°C	
T <sub>L</sub>	Max Lead Temp for Soldering:0.063" from case for 10 sec				300		
Torque	Mounting torque (Mounting = 8-32 or 4mm Machine and terminals = 4mm Machine)				1.5	N.m	
Wt	Package Weight			29.2		g	

### **Typical IGBT Performance Curve**



APT100GT120JU3 - Rev 2 October, 2012





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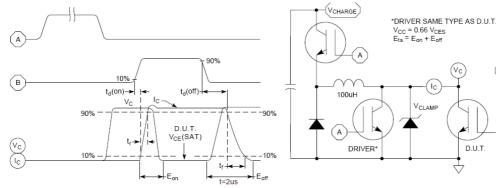


Figure 15, Switching Loss Test Circuit and Waveforms

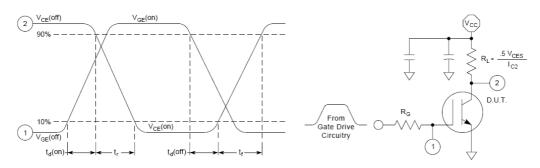
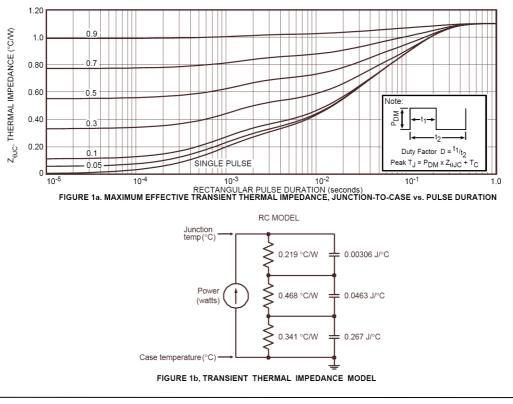


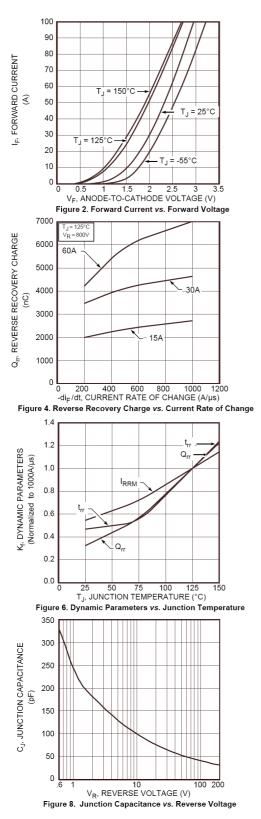
Figure 16, Resistive Switching Time Test Circuit and Waveforms



**Typical Diode Performance Curve** 

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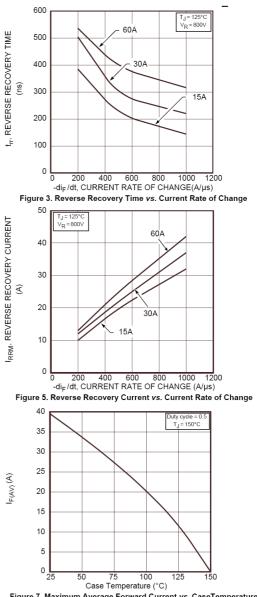
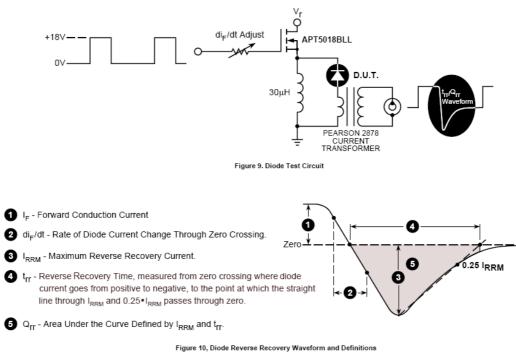
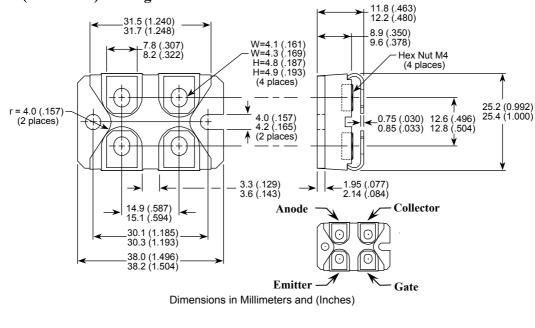


Figure 7. Maximum Average Forward Current vs. CaseTemperature





## SOT-227 (ISOTOP<sup>®</sup>) Package Outline



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